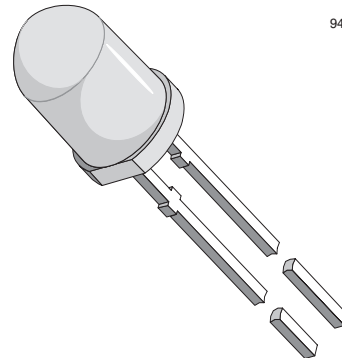


Ultrabright LED, \varnothing 5 mm Untinted Non-Diffused

Description

The TLC.58.. series is a clear, non diffused 5 mm LED for high end applications where supreme luminous intensity and a very small emission angle is required. These lamps with clear untinted plastic case utilize the highly developed ultrabright AllnGaP and GaP technologies.

The very small viewing angle of these devices provide a very high luminous intensity.



94 8631

Features

- Untinted non diffused lens
- Utilizing ultrabright AllnGaP and InGaN technology
- Very high luminous intensity
- Very small emission angle
- High operating temperature: T_j (chip junction temperature) up to 125 °C for AllnGaP devices
- Luminous intensity and color categorized for each packing unit
- ESD-withstand voltage: 2 kV acc. to MIL STD 883 D, Method 3015.7 for AllnGaP, 1 kV for InGaN

Applications

- Interior and exterior lighting
- Outdoor LED panels, displays
- Instrumentation and front panel indicators
- Central high mounted stop lights (CHMSL) for motor vehicles
- Replaces incandescent lamps
- Traffic signals and signs
- Light guide design

Parts Table

| Part | Color, Luminous Intensity | Technology |
|-----------|------------------------------|----------------|
| TLCR5800 | Red, $I_V > 7500$ mcd | AllGaP on GaAs |
| TLCY5800 | Yellow, $I_V > 5750$ mcd | AllGaP on GaAs |
| TLCTG5800 | True green, $I_V > 2400$ mcd | InGaN on SiC |
| TLCB5800 | Blue, $I_V > 750$ mcd | InGaN on SiC |

Absolute Maximum Ratings

$T_{amb} = 25$ °C, unless otherwise specified

TLCR5800 , TLCY5800 , TLCTG5800 , TLCB5800

| Parameter | Test condition | Part | Symbol | Value | Unit |
|--------------------|----------------------|-----------|--------|-------|------|
| Reverse voltage | | | V_R | 5 | V |
| DC forward current | $T_{amb} \leq 85$ °C | TLCR5800 | I_F | 50 | mA |
| | $T_{amb} \leq 85$ °C | TLCR5800 | I_F | 50 | mA |
| | $T_{amb} \leq 60$ °C | TLCTG5800 | I_F | 30 | mA |
| | $T_{amb} \leq 60$ °C | TLCTG5800 | I_F | 30 | mA |

| Parameter | Test condition | Part | Symbol | Value | Unit |
|-------------------------------------|------------------------------|-----------|------------|---------------|------------|
| Surge forward current | $t_p \leq 10 \mu s$ | TLCR5800 | I_{FSM} | 1 | A |
| | $t_p \leq 10 \mu s$ | TLCR5800 | I_{FSM} | 1 | A |
| | $t_p \leq 10 \mu s$ | TLCTG5800 | I_{FSM} | 0.1 | A |
| | $t_p \leq 10 \mu s$ | TLCTG5800 | I_{FSM} | 0.1 | A |
| Power dissipation | $T_{amb} \leq 85^\circ C$ | TLCR5800 | P_V | 135 | mW |
| | $T_{amb} \leq 85^\circ C$ | TLCR5800 | P_V | 135 | mW |
| | $T_{amb} \leq 60^\circ C$ | TLCTG5800 | P_V | 135 | mW |
| | $T_{amb} \leq 60^\circ C$ | TLCTG5800 | P_V | 135 | mW |
| Junction temperature | | TLCR5800 | T_j | 125 | $^\circ C$ |
| | | TLCR5800 | T_j | 125 | $^\circ C$ |
| | | TLCTG5800 | T_j | 100 | $^\circ C$ |
| | | TLCTG5800 | T_j | 100 | $^\circ C$ |
| Operating temperature range | | | T_{amb} | - 40 to + 100 | $^\circ C$ |
| Storage temperature range | | | T_{stg} | - 40 to + 100 | $^\circ C$ |
| Soldering temperature | $t \leq 5 s, 2 mm$ from body | | T_{sd} | 260 | $^\circ C$ |
| Thermal resistance junction/ambient | | | R_{thJA} | 300 | K/W |

Optical and Electrical Characteristics

$T_{amb} = 25^\circ C$, unless otherwise specified

Red

TLCR5800

| Parameter | Test condition | Part | Symbol | Min | Typ. | Max | Unit |
|--|------------------|----------|------------------|------|---------|-----|------|
| Luminous intensity ¹⁾ | $I_F = 50 mA$ | TLCR5800 | I_V | 7500 | 20000 | | |
| Dominant wavelength | $I_F = 50 mA$ | | λ_d | 611 | 616 | 622 | nm |
| Peak wavelength | $I_F = 50 mA$ | | λ_p | | 622 | | nm |
| Spectral bandwidth at 50 % $I_{rel max}$ | $I_F = 50 mA$ | | $\Delta\lambda$ | | 18 | | nm |
| Angle of half intensity | $I_F = 50 mA$ | | ϕ | | ± 4 | | deg |
| Forward voltage | $I_F = 50 mA$ | | V_F | | 2.1 | 2.7 | V |
| Reverse voltage | $I_R = 10 \mu A$ | | V_R | 5 | | | V |
| Temperature coefficient of V_F | $I_F = 50 mA$ | | TC_{VF} | | - 3.5 | | mV/K |
| Temperature coefficient of λ_d | $I_F = 50 mA$ | | $TC_{\lambda d}$ | | 0.05 | | nm/K |

¹⁾ in one Packing Unit $I_{VMax}/I_{VMin} \leq 1.6$

Yellow
TLCY5800

| Parameter | Test condition | Part | Symbol | Min | Typ. | Max | Unit |
|--|------------------------|----------|------------------|------|---------|-----|------|
| Luminous intensity ¹⁾ | $I_F = 50 \text{ mA}$ | TLCY5800 | I_V | 5750 | 14000 | | mcd |
| Dominant wavelength | $I_F = 50 \text{ mA}$ | | λ_d | 585 | 590 | 597 | nm |
| Peak wavelength | $I_F = 50 \text{ mA}$ | | λ_p | | 593 | | nm |
| Spectral bandwidth at 50 % $I_{rel \text{ max}}$ | $I_F = 50 \text{ mA}$ | | $\Delta\lambda$ | | 17 | | nm |
| Angle of half intensity | $I_F = 50 \text{ mA}$ | | φ | | ± 4 | | deg |
| Forward voltage | $I_F = 50 \text{ mA}$ | | V_F | | 2.1 | 2.7 | V |
| Reverse voltage | $I_R = 10 \mu\text{A}$ | | V_R | 5 | | | V |
| Temperature coefficient of V_F | $I_F = 50 \text{ mA}$ | | TC_{V_F} | | - 3.5 | | mV/K |
| Temperature coefficient of λ_d | $I_F = 50 \text{ mA}$ | | TC_{λ_d} | | 0.1 | | nm/K |

¹⁾ in one Packing Unit $I_{V_{Max}}/I_{V_{Min}} \leq 1.6$

Pure green

| Parameter | Test condition | Part | Symbol | Min | Typ. | Max | Unit |
|--|------------------------|-----------|------------------|------|---------|-----|------|
| Luminous intensity ¹⁾ | $I_F = 30 \text{ mA}$ | TLCTG5800 | I_V | 2400 | 7000 | | mcd |
| Dominant wavelength | $I_F = 30 \text{ mA}$ | | λ_d | 515 | 525 | 535 | nm |
| Peak wavelength | $I_F = 30 \text{ mA}$ | | λ_p | | 520 | | nm |
| Spectral bandwidth at 50 % $I_{rel \text{ max}}$ | $I_F = 30 \text{ mA}$ | | $\Delta\lambda$ | | 37 | | nm |
| Angle of half intensity | $I_F = 30 \text{ mA}$ | | φ | | ± 4 | | deg |
| Forward voltage | $I_F = 30 \text{ mA}$ | | V_F | | 3.9 | 4.5 | V |
| Reverse voltage | $I_R = 10 \mu\text{A}$ | | V_R | 5 | | | V |
| Temperature coefficient of V_F | $I_F = 30 \text{ mA}$ | | TC_{V_F} | | - 4.5 | | mV/K |
| Temperature coefficient of λ_d | $I_F = 30 \text{ mA}$ | | TC_{λ_d} | | 0.02 | | nm/K |

¹⁾ in one Packing Unit $I_{V_{Max}}/I_{V_{Min}} \leq 1.6$

Blue
TLCB5800

| Parameter | Test condition | Part | Symbol | Min | Typ. | Max | Unit |
|--|------------------------|----------|------------------|-----|---------|-----|------|
| Luminous intensity ¹⁾ | $I_F = 30 \text{ mA}$ | TLCB5800 | I_V | 750 | 2500 | | mcd |
| Dominant wavelength | $I_F = 30 \text{ mA}$ | | λ_d | 462 | 470 | 476 | nm |
| Peak wavelength | $I_F = 30 \text{ mA}$ | | λ_p | | 464 | | nm |
| Spectral bandwidth at 50 % $I_{rel \text{ max}}$ | $I_F = 30 \text{ mA}$ | | $\Delta\lambda$ | | 25 | | nm |
| Angle of half intensity | $I_F = 30 \text{ mA}$ | | φ | | ± 4 | | deg |
| Forward voltage | $I_F = 30 \text{ mA}$ | | V_F | | 3.9 | 4.5 | V |
| Reverse voltage | $I_R = 10 \mu\text{A}$ | | V_R | 5 | | | V |
| Temperature coefficient of V_F | $I_F = 30 \text{ mA}$ | | TC_{V_F} | | - 5.0 | | mV/K |
| Temperature coefficient of λ_d | $I_F = 30 \text{ mA}$ | | TC_{λ_d} | | 0.02 | | nm/K |

¹⁾ in one Packing Unit $I_{V_{Max}}/I_{V_{Min}} \leq 1.6$

Typical Characteristics ($T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

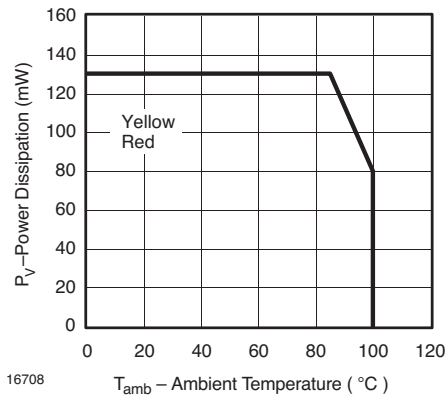


Figure 1. Power Dissipation vs. Ambient Temperature

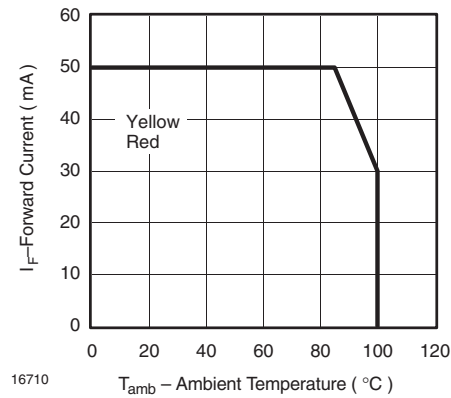


Figure 4. Forward Current vs. Ambient Temperature

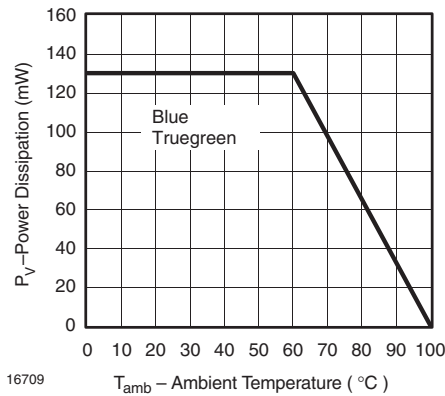


Figure 2. Power Dissipation vs. Ambient Temperature

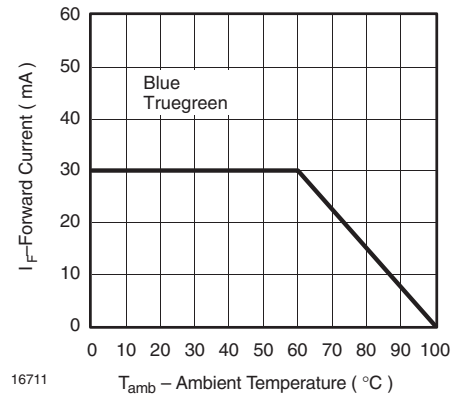


Figure 5. Forward Current vs. Ambient Temperature

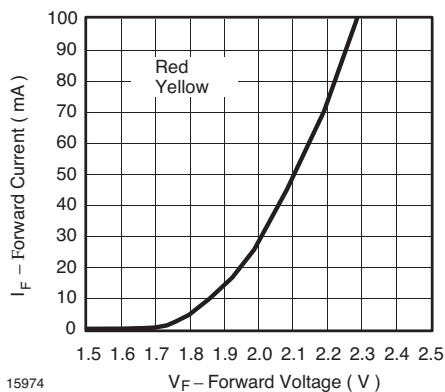


Figure 3. Forward Current vs. Forward Voltage

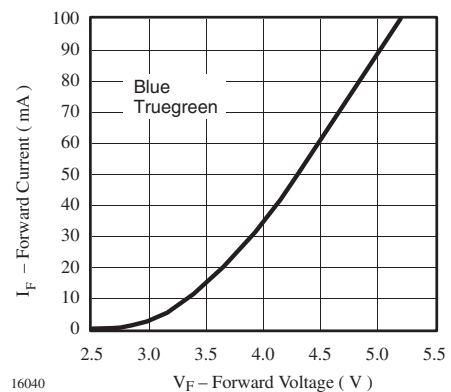


Figure 6. Forward Current vs. Forward Voltage

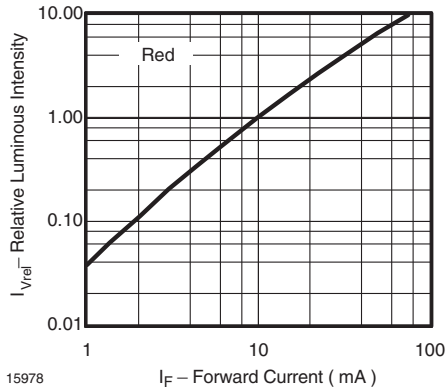


Figure 7. Relative Luminous Flux vs. Forward Current

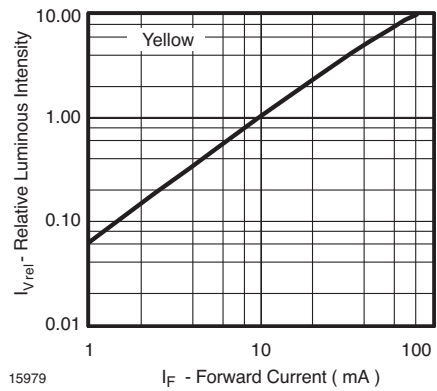


Figure 10. Relative Luminous Flux vs. Forward Current

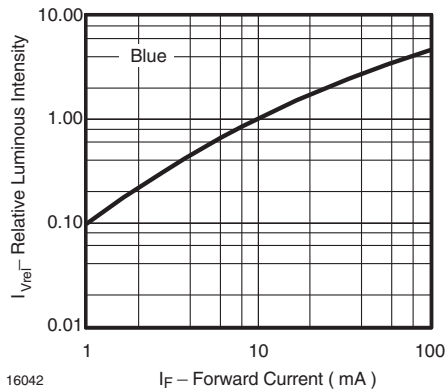


Figure 8. Relative Luminous Flux vs. Forward Current

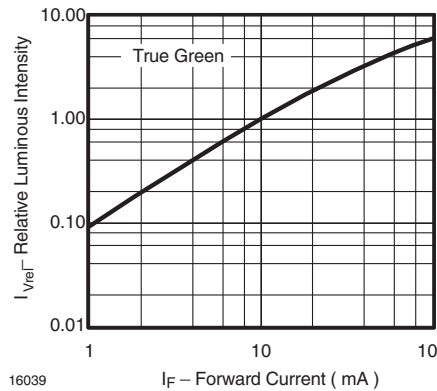


Figure 11. Relative Luminous Flux vs. Forward Current

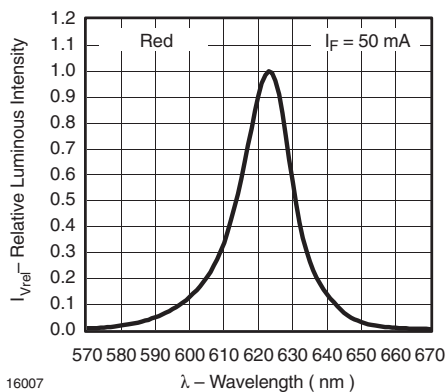


Figure 9. Relative Intensity vs. Wavelength

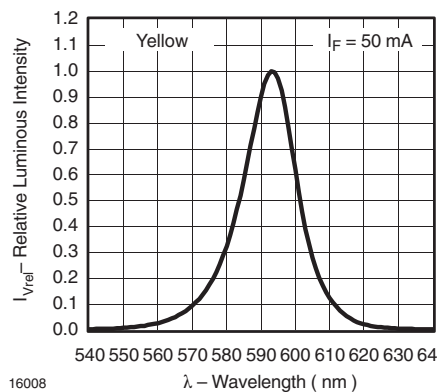


Figure 12. Relative Intensity vs. Wavelength

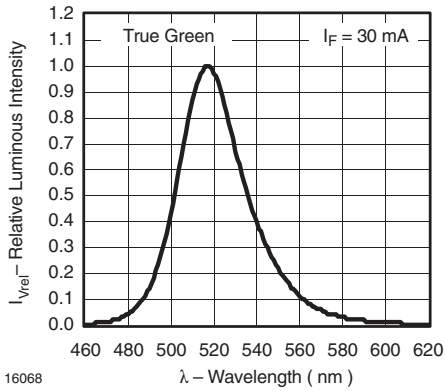


Figure 13. Relative Intensity vs. Wavelength

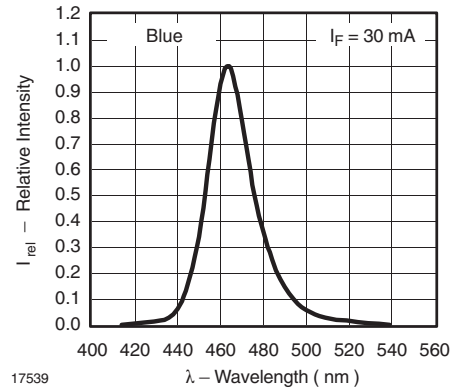
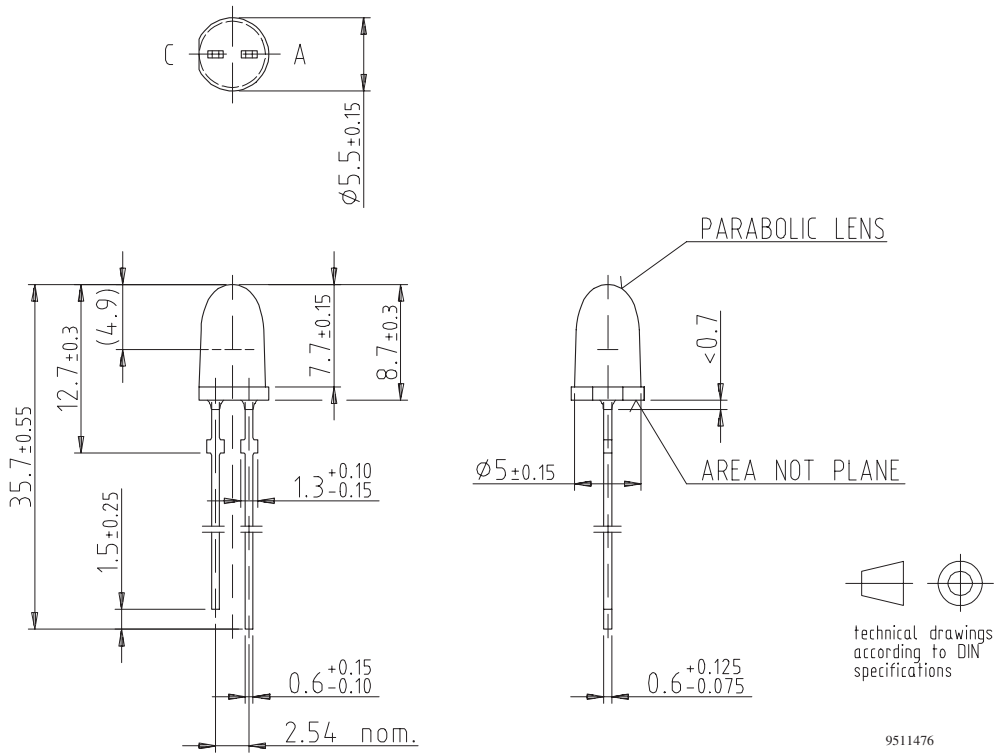


Figure 14. Relative Intensity vs. Wavelength

Package Dimensions in mm



Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design
and may do so without further notice.**

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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Электрон
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